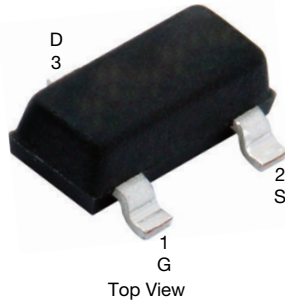
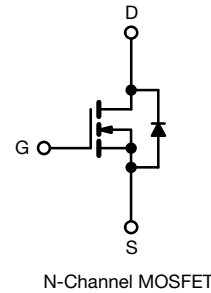


N-Channel 30 V (D-S) MOSFET

SOT-23 (TO-236)

FEATURES

- TrenchFET® power MOSFET
- 100 % R_g and UIS tested
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


RoHS
 COMPLIANT
 HALOGEN
FREE
 Available


PRODUCT SUMMARY	
V _{DS} (V)	30
R _{DS(on)} max. (Ω) at V _{GS} = 10 V	0.047
R _{DS(on)} max. (Ω) at V _{GS} = 4.5 V	0.065
Q _g typ. (nC)	3.0
I _D (A)	4.0
Configuration	Single

ORDERING INFORMATION	
Package	SOT-23 (TO-236)
Lead (Pb)-free	Si2306BDS-T1-E3
Lead (Pb)-free and halogen-free	Si2306BDS-T1-GE3

ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C, unless otherwise noted)				
PARAMETER	SYMBOL	LIMIT	UNIT	
Drain-source voltage	V _{DS}	30	V	
Gate-source voltage	V _{GS}	± 20		
Continuous drain current (T _J = 150 °C) ^{a, b}	I _D	T _A = 25 °C	4.0 ^c	A
		T _A = 70 °C	3.5 ^c	
		T _A = 25 °C	3.16 ^d	
		T _A = 70 °C	2.7 ^d	
Pulsed drain current	I _{DM}	20		
Continuous source-drain diode current ^{a, b}	I _S		1.04 ^c	
			0.62 ^d	
Maximum power dissipation ^{a, b}	P _D	T _A = 25 °C	1.25 ^c	W
		T _A = 70 °C	0.8 ^c	
		T _A = 25 °C	0.75 ^d	
		T _A = 70 °C	0.48 ^d	
Operating junction and storage temperature range	T _J , T _{stg}	-55 to +150	°C	

Notes

- Surface mounted on 1" x 1" FR4 board, t ≤ 5 s
- Pulse width limited by maximum junction temperature
- t = 5 s
- Steady state



THERMAL RESISTANCE RATINGS					
PARAMETER		SYMBOL	TYPICAL	MAXIMUM	UNIT
Maximum junction-to-ambient ^a	t ≤ 5 s	R _{thJA}	60	100	°C/W
	Steady state		130	166	
Maximum junction-to-foot (drain)	Steady state	R _{thJF}	60	75	

Note

a. Surface mounted on 1" x 1" FR4 board

SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Static						
Drain-source breakdown voltage	V _{DS}	V _{GS} = 0 V, I _D = 250 μA	30	-	-	V
Gate-source threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250 μA	1.0	-	3.0	V
Gate-body leakage	I _{GSS}	V _{DS} = 0 V, V _{GS} = ± 20 V	-	-	± 100	nA
Zero gate voltage drain current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V	-	-	0.5	μA
		V _{DS} = 30 V, V _{GS} = 0 V, T _J = 55 °C	-	-	10	
On-state drain current ^a	I _{D(on)}	V _{DS} ≥ 4.5 V, V _{GS} = 10 V	6	-	-	A
Drain-source on-state resistance ^a	R _{DS(on)}	V _{GS} = 10 V, I _D = 3.5 A	-	0.038	0.047	Ω
		V _{GS} = 4.5 V, I _D = 2.8 A	-	0.052	0.065	
Forward transconductance ^a	g _{fs}	V _{DS} = 4.5 V, I _D = 2.5 A	-	7.0	-	S
Diode forward voltage	V _{SD}	V _{GS} = 0 V, I _S = 1.25 A	-	0.8	1.2	V
Dynamic						
Gate charge	Q _g	V _{DS} = 15 V, V _{GS} = 5 V, I _D = 2.5 A	-	3.0	4.5	nC
Total gate charge	Q _{gt}	V _{DS} = 15 V, V _{GS} = 10 V, I _D = 2.5 A	-	6	9	
Gate-source charge	Q _{gs}		-	1.6	-	
Gate-drain charge	Q _{gd}		-	0.6	-	
Gate resistance	R _g	f = 1 MHz	2.0	5.0	7.5	Ω
Input capacitance	C _{iss}	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz	-	305	-	pF
Output capacitance	C _{oss}		-	65	-	
Reverse transfer capacitance	C _{rss}		-	29	-	
Switching						
Turn-on delay time	t _{d(on)}	V _{DD} = 15 V, R _L = 15 Ω, I _D ≅ 1 A, V _{GEN} = 0 V, R _g = 6 Ω	-	7	11	ns
Rise time	t _r		-	12	18	
Turn-off delay time	t _{d(off)}		-	14	25	
Fall time	t _f		-	6	10	
Reverse recovery time	t _{rr}	I _F = 1.25 A, di/dt = 100 A/μs	-	14	21	nC
Body diode reverse recovery charge	Q _{rr}		-	6	10	

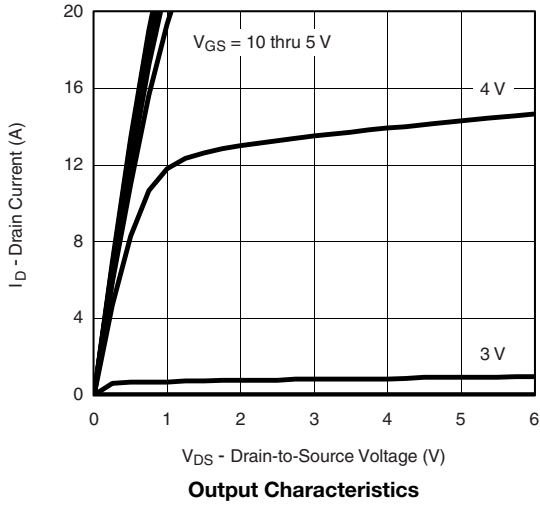
Notes

a. Pulse test; pulse width ≤ 300 μs, duty cycle ≤ 2 %

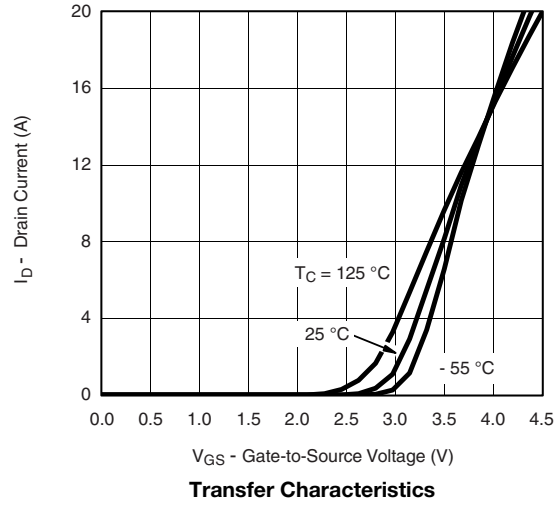
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



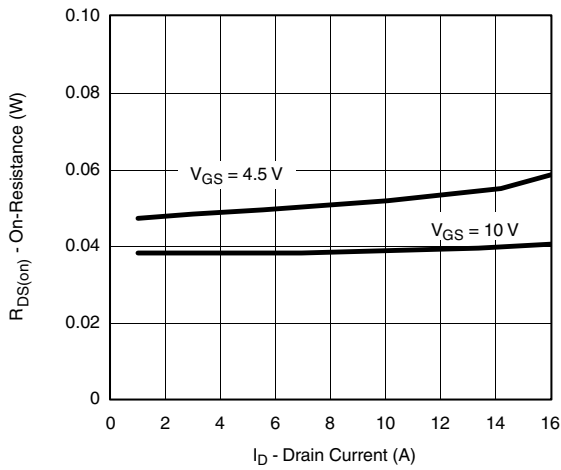
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



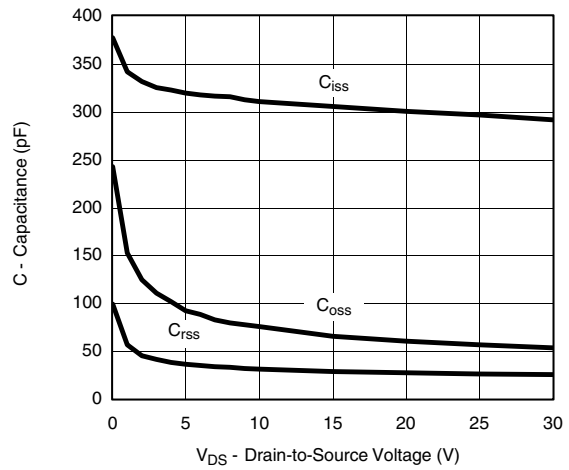
Output Characteristics



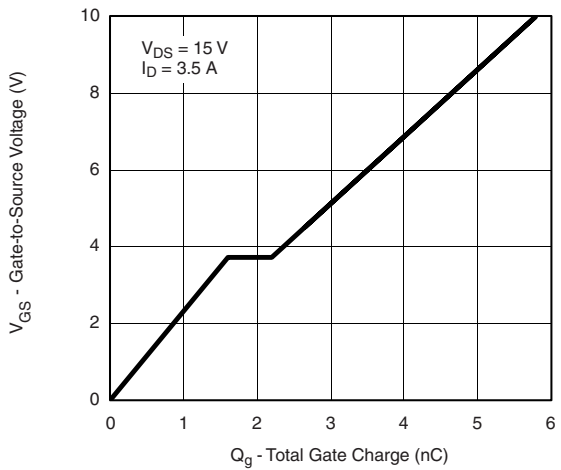
Transfer Characteristics



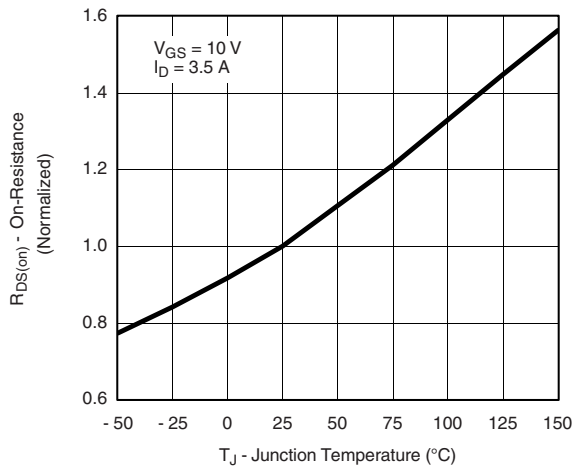
On-Resistance vs. Drain Current



Capacitance



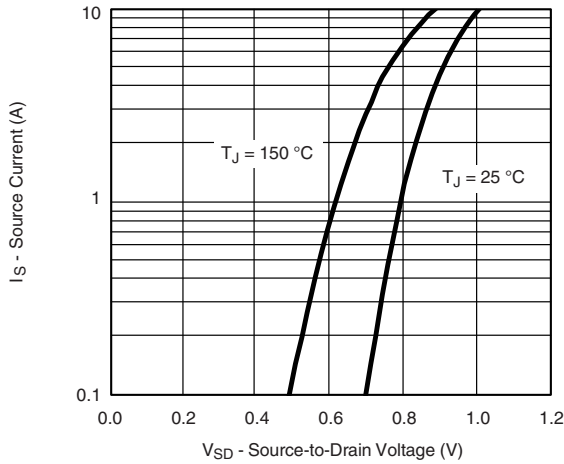
Gate Charge



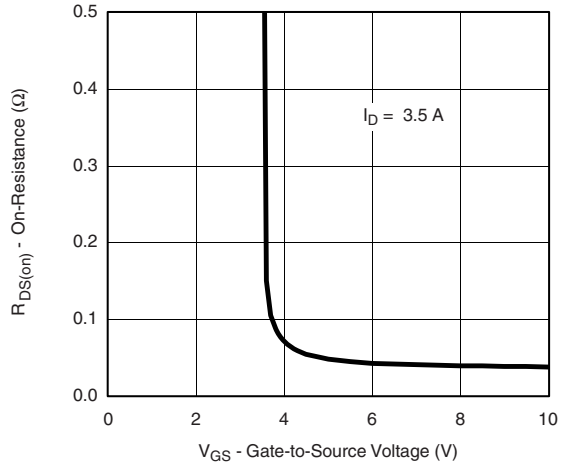
On-Resistance vs. Junction Temperature



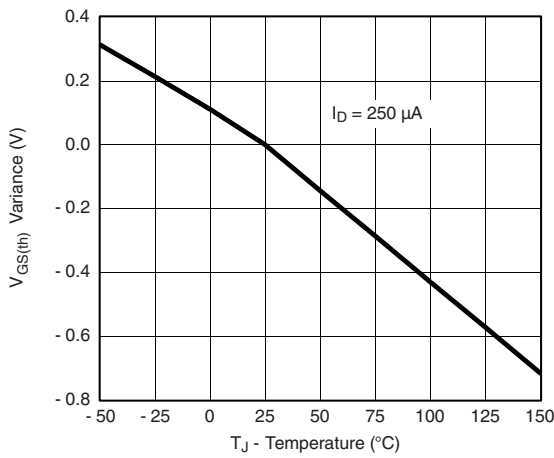
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



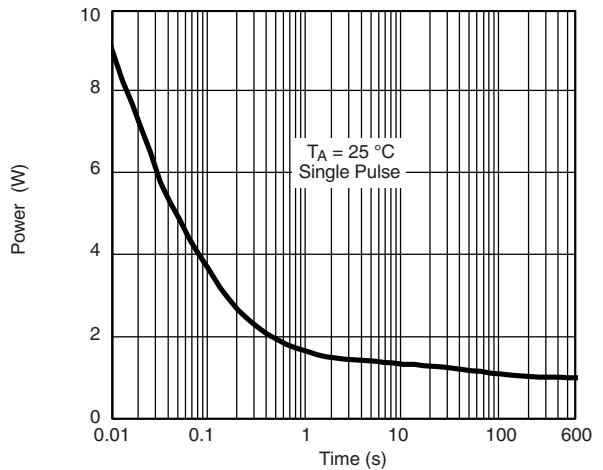
Source-Drain Diode Forward Voltage



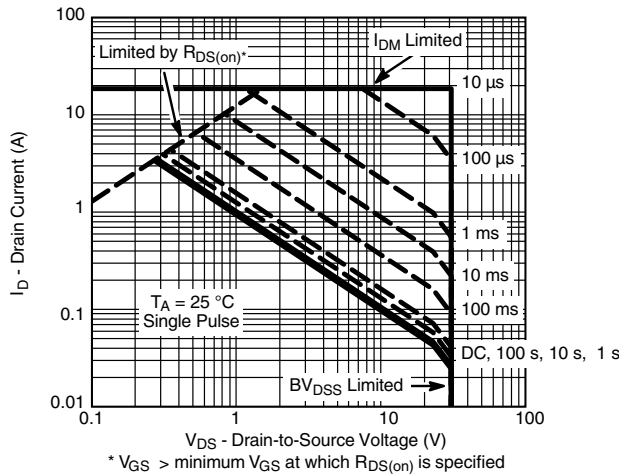
On-Resistance vs. Gate-to-Source Voltage



Threshold Voltage



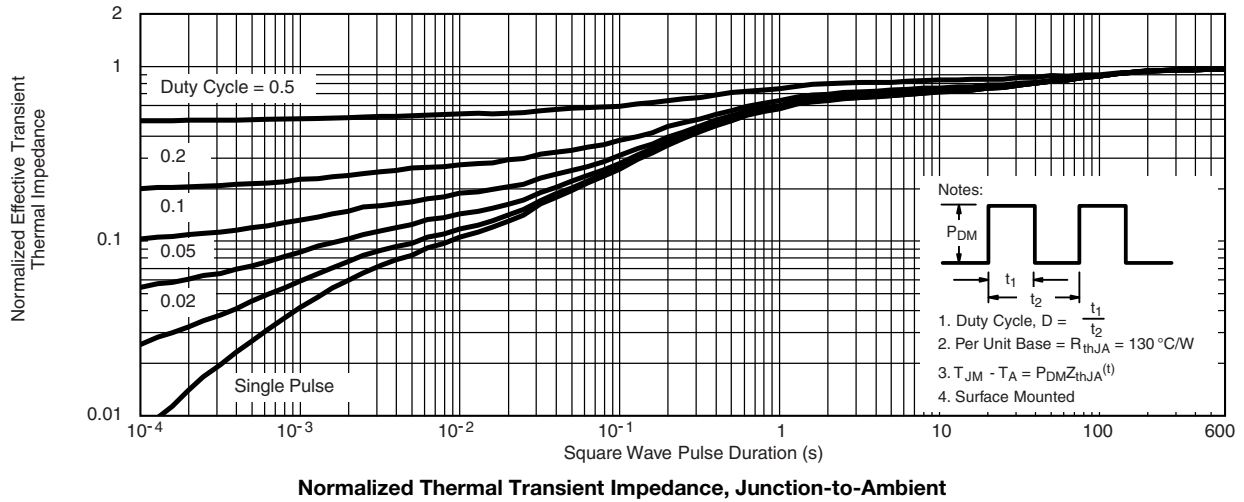
Single Pulse Power



Safe Operating Area



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?73234.

SOT-23 (TO-236): 3-LEAD



Dim	MILLIMETERS		INCHES	
	Min	Max	Min	Max
A	0.89	1.12	0.035	0.044
A ₁	0.01	0.10	0.0004	0.004
A ₂	0.88	1.02	0.0346	0.040
b	0.35	0.50	0.014	0.020
c	0.085	0.18	0.003	0.007
D	2.80	3.04	0.110	0.120
E	2.10	2.64	0.083	0.104
E ₁	1.20	1.40	0.047	0.055
e	0.95 BSC		0.0374 Ref	
e ₁	1.90 BSC		0.0748 Ref	
L	0.40	0.60	0.016	0.024
L ₁	0.64 Ref		0.025 Ref	
S	0.50 Ref		0.020 Ref	
q	3°	8°	3°	8°

ECN: S-03946-Rev. K, 09-Jul-01
 DWG: 5479

RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads
Dimensions in Inches/(mm)

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